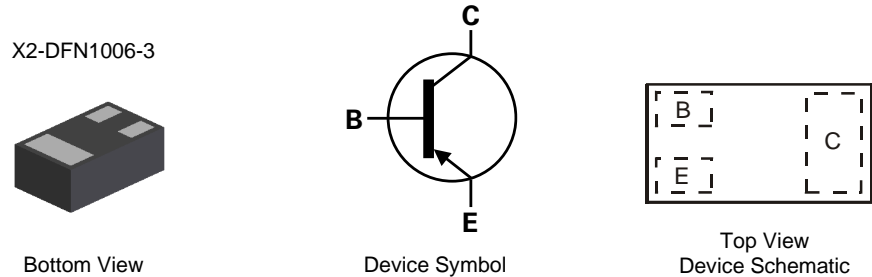


## Features

- $BV_{CEO} > -45V$
- $I_C = -100mA$  High Collector Current
- $P_D = 1W$  Power Dissipation
- $0.6mm^2$  Package Footprint, 13 Times Smaller than SOT23
- 0.4mm Height Package Minimizing Off-Board Profile
- Complementary NPN Type: BC847BLP4
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.**  
<https://www.diodes.com/quality/product-definitions/>
- **An automotive-compliant part is available under separate datasheet ([BC857BLP4Q](#))**

## Mechanical Data

- Package: X2-DFN1006-3
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu. Solderable per MIL-STD-202, Method 208 <sup>(e4)</sup>
- Weight: 0.0008 grams (Approximate)

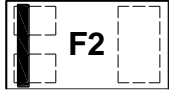
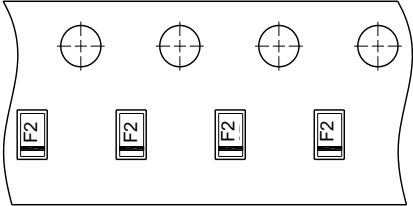
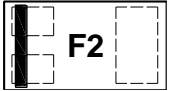
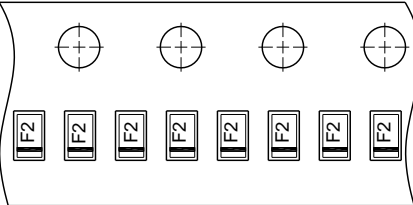


## Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
BC857BLP4-7	X2-DFN1006-3	F2	7	8	3,000	Reel
BC857BLP4-7B	X2-DFN1006-3	F2	7	8	10,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**

<p><b>BC857BLP4-7</b></p>	 <p><b>F2</b> F2 = Product Type Marking Code</p> <p>Top View Bar Denotes Base and Emitter Side</p> 
<p><b>BC857BLP4-7B</b></p>	 <p><b>F2</b> F2 = Product Type Marking Code</p> <p>Top View Bar Denotes Base and Emitter Side</p> 

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-45	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current	I <sub>C</sub>	-100	mA
Peak Pulse Collector Current	I <sub>CM</sub>	-200	mA

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	0.4	W
		1	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	310	°C/W
		120	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	120	°C/W
Operating and Storage and Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	200	V	B

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-50	—	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-45	—	—	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -100μA
DC Current Gain	h <sub>FE</sub>	220	300	475	—	V <sub>CE</sub> = -5V, I <sub>C</sub> = -2mA
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	—	-90	-300	mV	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA
		—	-250	-650		I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	—	-700	—	mV	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA
		—	-850	—		I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA
Base-Emitter Voltage (Note 9)	V <sub>BE(on)</sub>	-600	-670	-750	mV	V <sub>CE</sub> = -5V, I <sub>C</sub> = -2mA
		—	-710	-820		V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA
Collector-Cutoff Current	I <sub>CBO</sub>	—	—	-15	nA	V <sub>CB</sub> = -30V
		—	—	-4.0		μA
Gain Bandwidth Product	f <sub>T</sub>	100	—	—	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA f = 100MHz
Collector-Base Capacitance	C <sub>CBO</sub>	—	3.0	—	pF	V <sub>CB</sub> = -10V, f = 1MHz

- Notes:
- For the device mounted on minimum recommended pad layout 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition.
  - Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
  - Thermal resistance from junction to solder-point (on the exposed collector pad).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.
  - Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

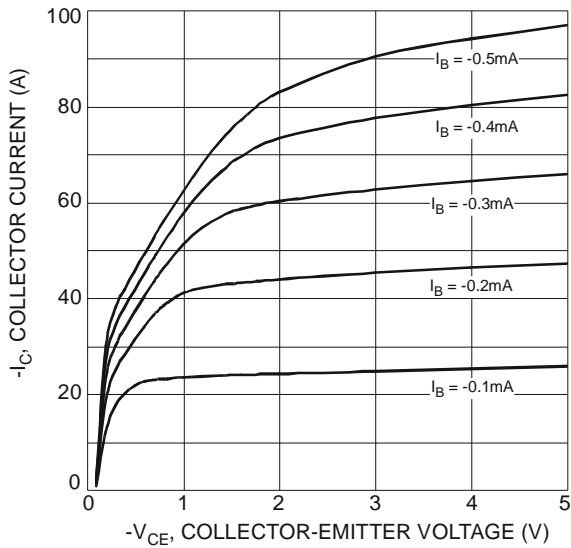


Figure 1. Typical Collector Current vs. Collector-Emitter Voltage

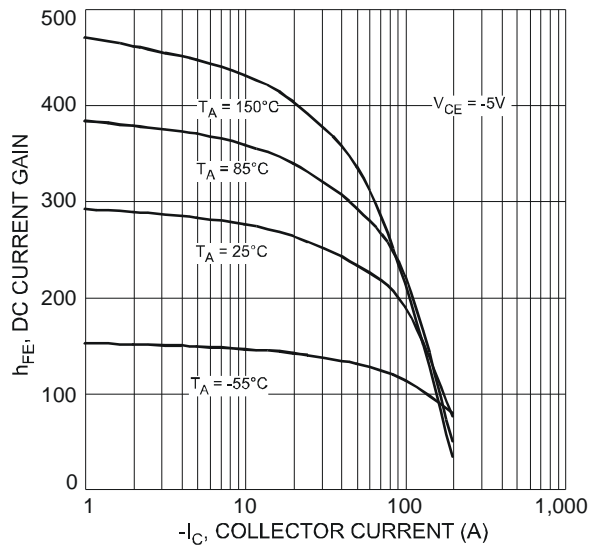


Figure 2. Typical DC Current Gain vs. Collector Current

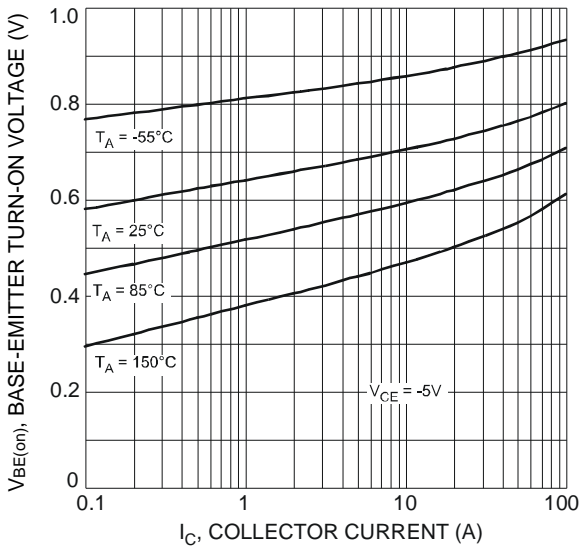


Figure 3. Typical Base-Emitter Turn-On Voltage vs. Collector Current

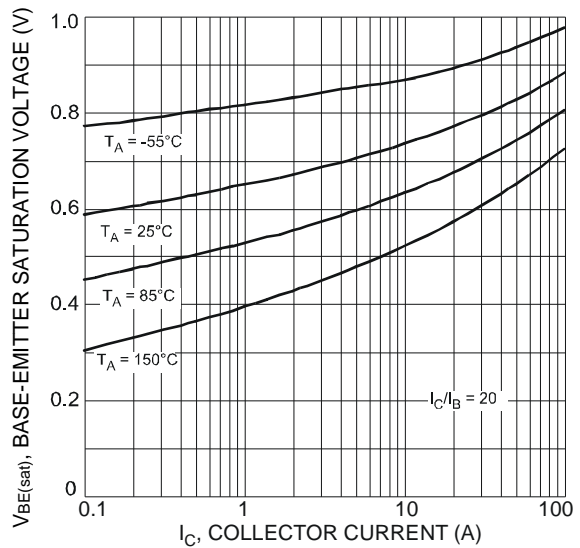
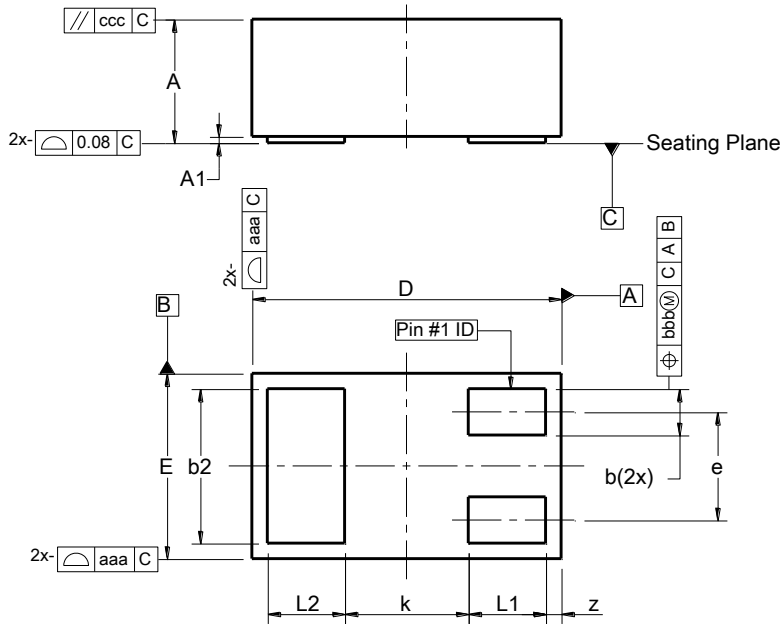


Figure 4. Typical Base-Emitter Saturation Voltage vs. Collector Current

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**X2-DFN1006-3**

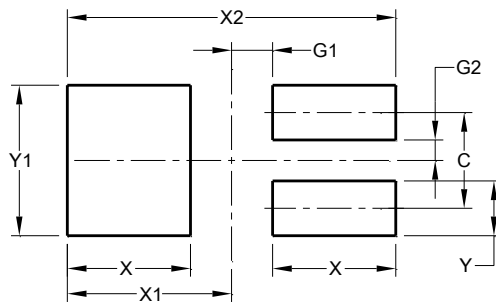


X2-DFN1006-3			
Dim	Min	Max	Typ
A	—	0.40	—
A1	0.00	0.05	0.03
b	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.05	1.00
E	0.55	0.65	0.60
e	-	-	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
k	-	-	0.40
z	0.02	0.08	0.05
aaa	0.15		
bbb	0.05		
ccc	0.05		
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**X2-DFN1006-3**



Dimensions	Value (in mm)
C	0.350
G1	0.150
G2	0.075
X	0.450
X1	0.600
X2	1.200
Y	0.200
Y1	0.550

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